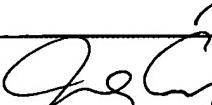


FORM PTO-1449 <u>LIST OF DOCUMENTS CITED BY APPLICANT</u>				Atty. Docket No. XA-9721A	Appln. No. 10/786,334		
				Applicant Keisuke TSUKAMOTO et al.			
				Filing Date February 26, 2004	Group 2811		
U.S. PATENT DOCUMENTS							
Examiner Initial		Document Number	Date	Name	Class	Sub-class	Filing Date
<i>Ch</i>	AA	5,251,168	10/5/93	Chung et al.	365	51	
<i>an</i>	AB	6,590,254	7/8/03	Tanaka (corrs. to Doc AL)	257	315	
<i>an</i>	AC	5,946,320	8/31/99	Shimizu et al. (corrs. to Doc AM)	365	185.01	
	AD						
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FOREIGN PATENT DOCUMENTS							
Examiner Initial		Document Number	Date	Country	Class	Sub-class	Translation
<i>an</i>	AL	2001-332708	11/30/01	Japan			Abstract
<i>an</i>	AM	11-97652	4/9/99	Japan			Abstract
<i>an</i>	AN	11-284134	10/15/99	Japan			Abstract
<i>an</i>	AO	11-54730	2/26/99	Japan			Abstract
<i>an</i>	AP	11-265891	9/28/99	Japan			Abstract
<i>an</i>	AQ	5-235366	9/10/93	Japan			Abstract
<i>an</i>	AR	2-111075	4/24/90	Japan			Abstract
	AS			/			
OTHER (including author, title, date, pertinent pages, etc.)							
	AT						
Examiner				Date Considered <i>4-14-05</i>			
EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; draw line through citation if not in conformance and not considered. Include copy of this form with next communication to Applicant.							

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Examiner Initial		Document Number	Date	Country	Class	Sub-class	Translation
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Ch	AP	Kim et al., "A Novel 4.6F ² NOR Cell Technology With Lightly Doped Source (LDS) Junction For High Density Flash Memories," IEDM (International Electron Devices Meeting), 1998, pp. 979-982.					
	AQ						
Examiner <i>JG</i>				Date Considered <i>4-14-05</i>			
EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; draw line through citation if not in conformance and not considered. Include copy of this form with next communication to Applicant.							